

5DABT D3 Series

Efficiency up to 85%

-40°C~+85°C

Dual Output Voltage

Temperature range:

Up to 3000VDC isolation

(F) Short circuit protection (SCP)

4.8W - Dual Output - Wide Input - Isolated & Regulated IGBT dedicated DC-DC converter

(+ Industry standard pinout

RoHS Compliance

DC-DC converter

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Output over-voltage protection

IGBT dedicated regulated



DC-DC Converter

The 1S4A Series are designed for applications where isolated output is required from a distributed power system.

4.8 Watt

These products apply to:

1) Input voltage range: ±10%Vin; 2) 1.5KVDC input to output isolation;

3) Regulated and low ripple noise is not required.

Such as: digital circuits, low frequency analog circuits, and relay drive circuits.



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Common specifications Short circuit protection: Continuous, automatic recovery Temperature rise at full load: 30°C TYP, 40°C MAX (Ta=25°C) Cooling: Free air convection Operation temperature range: -40°C - +85°C -55°C - +125°C Storage temperature range: 300°C MAX, 1.5mm from case for 10 sec Lead temperature Storage humidity range: < 95% Case material: Black flame-retardant and heat-resistant plastic [UL94-V0] >1,000,000 hours MTBF: Weight: 14g

Input specifications

Item	Test condition	Min	Тур	Max	Units
Input voltage	12VDC input24VDC input	-0.7 -0.7		25 50	VDC VDC
Starting voltage	12VDC input24VDC input			9 18	VDC VDC
Input filter	Capacitor				

Isolation specifications

Item	Test condition	Min	Тур	Max	Units
Isolation voltage	Input-Output, tested for 1 minute and leakage current less than 1mA	3000			VDC
Isolation resistance	Input-Output, test at 500VDC	1000			MΩ
Isolation capacitance	Input/Output, 100KHz/0.1V		100		pF

EMC specifications EMI CE CISPR22/EN55022 CLASS B (External Circuit Refer to EMC recommended circuit) CISPR22/EN55022 EMI RE CLASS B (External Circuit Refer to EMC recommended circuit) ESD EMS IEC/EN61000-4-2 Contact ±8KV perf. Criteria B

Output specifications	5				
Item	Test condition	Min	Тур	Max	Units
Output power	Main output (+15V output)	0.24		4.8	W
Output voltage accuracy	 Supplement output (-9V output) Full load, Input volta- 		±1 ±3	±2 +5	%
	ge from low to high		ŦQ	±0	70
Line regulation	Input voltage varies by ±1%		±0.2	±0.5	%
Load regulation	5% to 100% load		±0.5	±1	%
Transient Recovery Time	25% load step change		0.5	2	μs
Transient Response Deviation	25% load step change		±2.5	±5	%
Temperature drift coefficient	100% load			±0.03	%/°C
Ripple & Noise*	20MHz Bandwidth		100	200	mVp-p
Switching frequency	Full load, nominal input		300		KHz
Output over-voltage protection		110	120	140	%Vo

*Test ripple and noise by "parallel cable" method. See detailed operation instructions at DC-DC application notes.

Model selection:

WCTP**_xxyyN##O

W= Watt; C= Case; T= Type; P= Pinning; **= Voltage Variation (omitted ± 10%); **xx**= Vin; **yy**= Vout; **N**= Numbers of Output; ##= Isolation (kVDC); **O**= output regulation

Example:

5DABT_121509D3P 5 = 4.8 Watt; D=DIP24; A=Pinning; BT= IGBT Serie; 12=12Vin; 15= +15Vout; 09= -9Vout; D=Dual Output; 3= 3KVDC; P= Short Circuit Protection (SCP)

sales@gaptec-electronic.com - www.gaptec-electronic.com

GAPTEC-Electronic GmbH & Co. KG

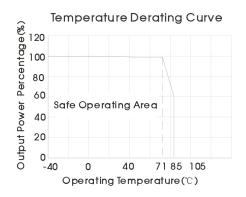
5DABT_D3 Series

4.8W - Dual Output - Wide Input - Isolated & Regulated IGBT dedicated DC-DC converter

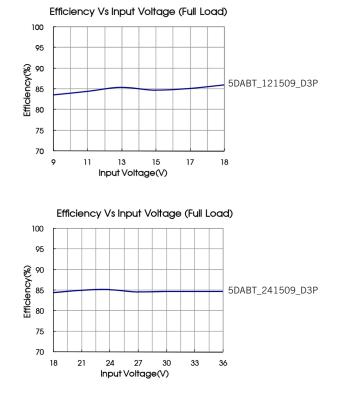
EMC sp	ecifications			
EMI	CE	CISPR22/EN55022	CLASS A	(see EMC recommended circuit,(2))
EMI	RE	CISPR22/EN55022	CLASS A	(see EMC recommended circuit,(2))
EMS	ESD	IEC/EN61000-4-2	Contact ±4KV	perf. Criteria B
EMS	RS	IEC/EN61000-4-3	10V/m	perf. Criteria A
EMS	EFT	IEC/EN61000-4-4 (see EMC recommende	±2KV ed circuit,①)	perf. Criteria B
EMS	Surge	IEC/EN61000-4-5 (see EMC recommende	±2KV ed circuit,①)	perf. Criteria B
EMS	CS	IEC/EN61000-4-6	3 Vr.m.s	perf. Criteria A
EMS	Voltage dips, short and interruptions immunity	IEC/EN61000-4-29	0%-70%	perf. Criteria B

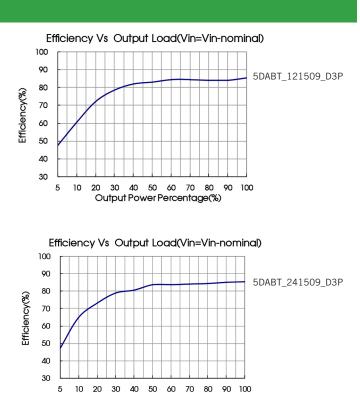
Part Number	Input Voltage [V]	Input current full load/ no load [mA, typ]	Output Voltage [VDC, +Vo/-Vo]	Output current [mA, +Vo/-Vo]	Max. capacitive load [µF]	Efficiency [%, typ]
5DABT_121509_D3P	12	471/16	+15/-9	±200/±10	1000	85
5DABT_241509_D3P	24	235/8	+15/-9	±200/±10	1000	85

Typical characteristics



Efficiency





Output Power Percentage(%)

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Recommended circuit

All the IGBT driver of this series are tested according to the recommended circuit (see Fig. 1) before delivery.

If it is required to further reduce input and output ripple, properly increase the input & output of additional capacitors Cin and Cout or select capacitors of low equivalent impedance provided that the capacitance is no larger than the max. capacitive load of the product.



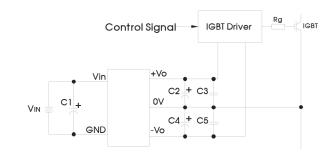
Figure 1

Vin	12V/24V
Cin	100µF
Cout	100µF

Typical application

Application Notes

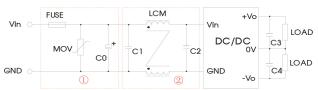
- 1. The wire between the converter and IGBT driver must as short as possible.
- 2. External filter capacitors should be connected as close as possible to the IGBT driver.
- 3. To ensure the high peak gate current, the filter capacitors should be electrolytic capacitor and ceramic capacitor collocation.
- 4. The output average power of the IGBT driver should be less than the output power of DC-DC module.



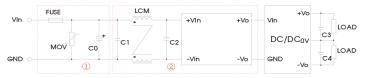
C1	100uF/63V(Electrolytic capacitor)
C2/C4	100uF/35V(Electrolytic capacitor)
C3/C5	10uF/25V(Ceramic capacitor)

EMC solution-recommended circuit

5DABT_121509_D3P



5DABT	24150	9 D38
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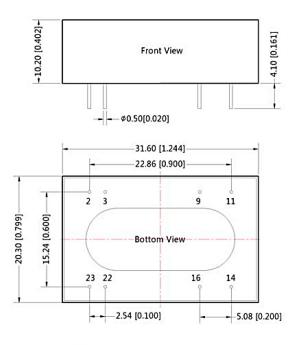
Parameters	5DABT_121509_D3P	5DABT_241509_D3P
FUSE	Choose according to p	practical input current
MOV	S14K25	S14K35
CO	680µF/25V	330µF/50V
C1, C2	4.7µI	F/50V
C3, C4	Refer to the Cout in	recommended circuit
LCM	1mH	3.3mH
Module		FT-AX1D

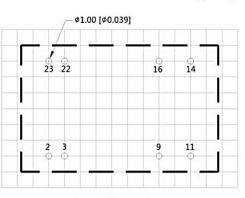
The product does not support output in parallel with power per liter or hot-swappable use.

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Mechanical dimensions





THIRD ANGLE PROJECTION

Note:Grid 2.54*2.54mm

Pin-C	Dut
Pin	Function
2,3	GND
9	٥v
11	-Vo
14	+Vo
16	0V
22,23	Vin

Note:

Unit: mm [inch] Pin diameter tolerances: ±0.10mm [±0.004inch] General tolerances: ±0.5mm [±0.020inch]

Note:

- 1. The lead connecting the power supply module and IGBT driver should be as short as possible during use;
- The output filtering capacitor should be as close as possible to the power supply module and IGBT driver;
- The peak of the IGBT driver gate drive current is high, so low internal resistance electrolytic capacitor is recommended to be used for the power supply module output filter capacitor;
- 4. The average output power of the driver must be lower than that of the power supply module;
- 5. Consider fixing with glue near the module if being used in vibration occasion;
- The max. capacitive load should be tested within the input voltage range and under full load conditions;
- 7. Unless otherwise noted, all specifications are measured at Ta= $25^\circ\text{C},$ humidity $<\!75\%,$ nominal input voltage and rated output load.
- In this datasheet, all test methods are based on our corporate standards.
 All characteristics are for listed models, and non-standard models may perform differently. Please contact our technical support for more detail.
- 10. Please contact our technical support for any specific requirement.
- 11. Specifications of this product are subject to changes without prior notice.